



Effect of Coulomb interations on the optical properties of doped graphene

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Motivation: Recent experiments by Z. Q. Li *et al.* Nature **4**, 532 (2008) regarding the optical conductivity in graphene:



Authors suggest a **possible mechanism**: electron-electron interaction combined with extrinsic effects such as impurities.

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Idea: The electronic properties of the Dirac point affects the optical properties of the doped system:

Im
$$\Sigma(\omega) = \begin{cases} a|\omega| + b & , |\omega| < \Lambda \\ a\Lambda + b & , |\omega| \ge \Lambda \end{cases}$$

Self energy ansatz

$$\operatorname{Re}\sigma(\omega) = g_s g_v \frac{e^2 v_F^2}{4\omega} \sum_{s,s'} \int \frac{dkk}{(2\pi)^2} \int d\epsilon \left[n_F(\epsilon) - n_F(\epsilon + \omega) \right] A_s(k,\omega) A_{s'}(k,\epsilon + \omega)$$

Kubo formula for the conductivity without vertex corrections.

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$$\omega \operatorname{Re} \sigma(\omega) \sim \operatorname{Im} \chi(\omega).$$

Electronic contribution to the **Raman** spectra.

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Results for a = 0.2, b = 0.001 eV, $\Lambda = 0.15 \text{ eV}$:

Optical conductivity:

